

# 1N4001G THRU 1N4007G, BY133G

DO-41

## **GLASS PASSIVATED JUNCTION RECTIFIER**

Reverse Voltage - 50 to 1300 Volts

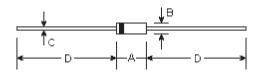
Forward Current - 1.0 Ampere

#### Features

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- High temperature metallurgically bonded construction
- Glass passivated cavity-free junction
- Capable of meeting environmental standards of MIL-S-19500
- 1.0 ampere operation at  $T_{A}=75^{\circ}C$  with no thermal runaway
- Typical I<sub>R</sub> less than 0.1 µ Â
- High temperature soldering guaranteed: 350°C/10 seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3Kg) tension

#### **Mechanical Data**

- Case: DO-41 molded plastic over glass body
- Terminals: Plated axial leads, solderable per MIL-STD-750, method 2026
- Polarity: Color band denotes cathode end
- Mounting Position: Any
- Weight: 0.012 ounce, 0.335 gram



DIMENSIONS										
DIM	inc	hes	m	Note						
	Min.	Max.	Min.	Max.	Note					
A	0.165	0.205	4.2	5.2						
В	0.079	0.106	2.0	2.7	ф					
С	0.028	0.034	0.71	0.86	ф					
D	1.000	-	25.40	-						

### **Maximum Ratings and Electrical Characteristics**

Ratings at 25°C ambient temperature unless otherwise specified.

	Symbols	1N 4001G	1N 4002G	1N 4003G	1N 4004G	1N 4005G	1N 4006G	1N 4007G	BY 133G	Units
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	1300	Volts
Maximum RMS voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	910	Volts
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	1300	Volts
Maximum average forward rectified current 0.375" (9.5mm) lead length at $T_{_A}\text{=}75^\circ\!\!\mathrm{C}$	I <sub>(AV)</sub>	1.0								Amp
Peak forward surge current 8.3mS single half sine-wave superimposed on rated load (MIL-STD-750D 4066 method)	I <sub>FSM</sub>	30.0							Amps	
Maximum instantaneous forward voltage at 1.0A	V <sub>F</sub>	1.1								Volts
$\begin{array}{llllllllllllllllllllllllllllllllllll$	I <sub>R</sub>	5.0 50.0							μА	
Typical reverse recovery time (Note 1)	T <sub>rr</sub>	2.0								μS
Typical junction capacitance (Note 2)	C	8.0								ρF
Typical thermal resistance (Note 3)	R <sub>☉ JA</sub> R <sub>☉ JL</sub>	55.0 25.0							°C/W	
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +175							°C	

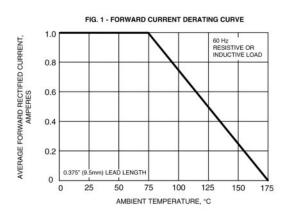
Notes:

(1) Reverse recovery test conditions: I<sub>E</sub>=0.5A, I<sub>R</sub>=1.0A, I<sub>rr</sub>=0.25A

(2) Measured at 1.0MHz and applied reverse voltage of 4.0 volts

(3) Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted





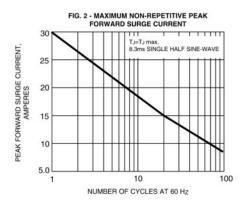
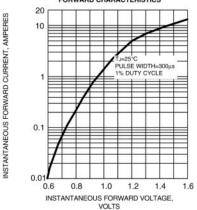


FIG. 3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



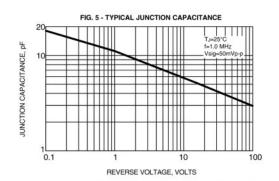


FIG. 4 - TYPICAL REVERSE CHARACTERISTICS

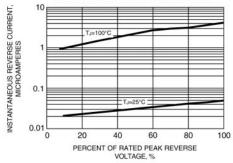


FIG. 6 - TYPICAL TRANSIENT THERMAL IMPEDANCE TRANSIENT THERMAL IMPEDANCE (°C/W) 100 Ш 10 1 0.1 0.01 0.1 1 10 100 t, PULSE DURATION, sec